MOSFETs Silicon N-channel MOS (U-MOSIX-H)

TPN2R903PL

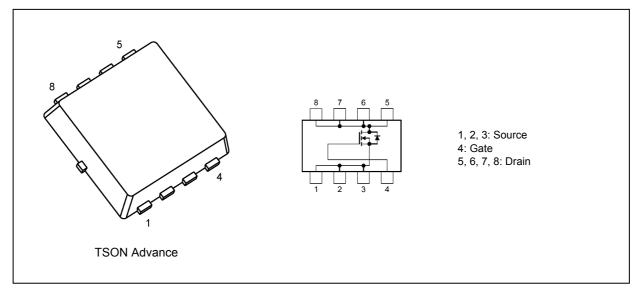
1. Applications

- High-Efficiency DC-DC Converters
- Switching Voltage Regulators
- Motor Drivers

2. Features

- (1) High-speed switching
- (2) Small gate charge: $Q_{SW} = 5.6 \text{ nC}$ (typ.)
- (3) Small output charge: $Q_{oss} = 17 \text{ nC}$ (typ.)
- (4) Low drain-source on-resistance: $R_{DS(ON)} = 2.1 \text{ m}\Omega$ (typ.) (V_{GS} = 10 V)
- (5) Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 30 \ V)$
- (6) Enhancement mode: V_{th} = 1.1 to 2.1 V (V_{DS} = 10 V, I_D = 0.2 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) (T_a = 25 °C unless otherwise specified)

Characterist	ics		Symbol	Rating	Unit
Drain-source voltage			V _{DSS}	30	V
Gate-source voltage		(Note 1)	V _{GSS}	±20	
Drain current (DC)	(T _c = 25 °C)	(Note 2)	Ι _D	70	A
Drain current (DC)	(Silicon limit)	(Note 2), (Note 3)	Ι _D	122	
Drain current (pulsed)	(t = 100 μs)	(Note 2)	I _{DP}	200	
Power dissipation	(T _c = 25 °C)		PD	75	W
Power dissipation		(Note 4)	PD	2.67	
Power dissipation		(Note 5)	PD	0.63	
Single-pulse avalanche energy		(Note 6)	E _{AS}	15	mJ
Single-pulse avalanche current		(Note 6)	I _{AS}	70	A
Channel temperature			T _{ch}	175	°C
Storage temperature			T _{stg}	-55 to 175	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

Characteristics			Symbol	Max	Unit
Channel-to-case thermal resistance	(T _c = 25 °C)		R _{th(ch-c)}	2.0	°C/W
Channel-to-ambient thermal resistance	(T _a = 25 °C)	(Note 4)	R _{th(ch-a)}	56	
Channel-to-ambient thermal resistance	(T _a = 25 °C)	(Note 5)	R _{th(ch-a)}	235	

Note 1: +20V /-16V ensured at DC condition.

-20V ensured at pulse condition(duty 5%).

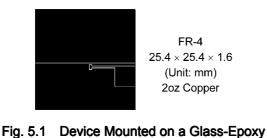
Note 2: Ensure that the channel temperature does not exceed 175 °C.

Note 3: Limited by silicon chip capability.

Note 4: Device mounted on a glass-epoxy board (a), Figure 5.1

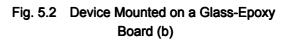
Note 5: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 6: V_{DD} = 24 V, T_{ch} = 25 °C (initial), L = 2.4 μ H, I_{AS} = 70 A



Board (a)

FR-4 25.4 × 25.4 × 1.6 (Unit: mm) 2oz Copper



Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

6.1. Static Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	V_{GS} = ±20 V, V_{DS} = 0 V	_		±0.1	μA
Drain cut-off current	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V	_		10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	30	_	—	V
Drain-source breakdown voltage (Note 7)	V _{(BR)DSX}	I _D = 10 mA, V _{GS} = -20 V	15	_	—]
Gate threshold voltage	V _{th}	V _{DS} = 10 V, I _D = 0.2 mA	1.1		2.1	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 4.5 V, I _D = 30 A	_	3.0	4.1	mΩ
		V _{GS} = 10 V, I _D = 35 A		2.1	2.9	

Note 7: If a reverse bias is applied between gate and source, this device enters V_{(BR)DSX} mode. Note that the drainsource breakdown voltage is lowered in this mode.

6.2. Dynamic Characteristics ($T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = 15 V, V _{GS} = 0 V, f = 1 MHz	_	1780	2300	pF
Reverse transfer capacitance	C _{rss}		—	60	115	
Output capacitance	C _{oss}			620	—	
Gate resistance	r _g	—	_	1.2	1.8	Ω
Switching time (rise time)	t _r	See Fig. 6.2.1	_	4.7	—	ns
Switching time (turn-on time)	t _{on}		_	12	—	
Switching time (fall time)	t _f]	_	8.2	_	
Switching time (turn-off time)	t _{off}		_	30	_	

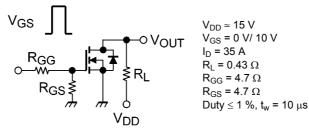


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25$ °C unless otherwise specified)

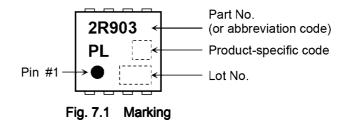
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus	Qg	$V_{DD}\approx 15~V,~V_{GS} \text{ = } 10~V,~I_{D} \text{ = } 35~A$	_	26	_	nC
gate-drain)		$V_{DD} \approx 15 \text{ V}, \text{ V}_{GS}$ = 4.5 V, I _D = 35 A	_	12	_	
Gate-source charge 1	Q _{gs1}	$V_{DD} \approx 15$ V, V_{GS} = 10 V, I_D = 35 A	_	5.9	_	
Gate-drain charge	Q _{gd}		_	2.5	_	
Gate switch charge	Q _{SW}		—	5.6	_	
Output charge	Q _{oss}	V_{DS} = 15 V, V_{GS} = 0 V, f = 1 MHz		17		

6.4. Source-Drain Characteristics ($T_a = 25$ °C unless otherwise specified)

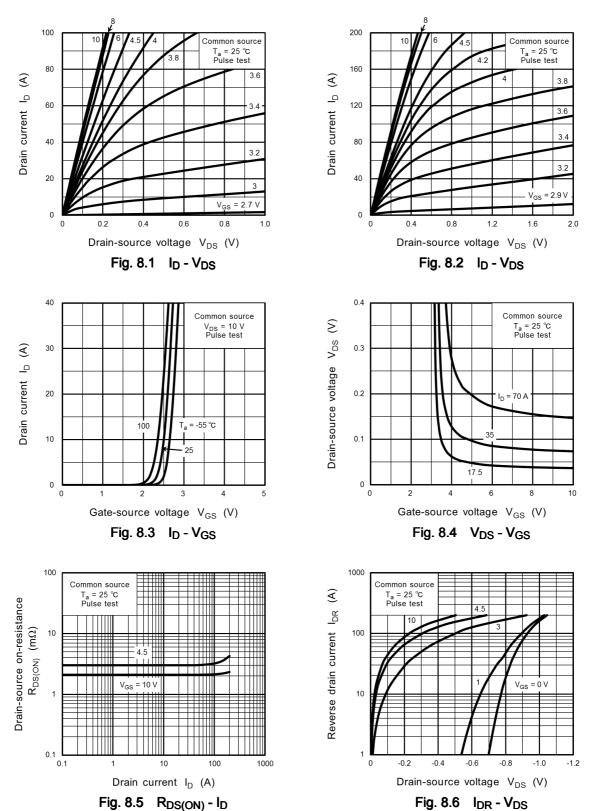
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (pulsed) (Note 8)	—	—	—	200	A
Diode forward voltage	V _{DSF}	I _{DR} = 70 A, V _{GS} = 0 V	_	_	-1.2	V
Reverse recovery time	t _{rr}	V _R = 15 V, I _{DR} = 17.5 A,	_	28	_	ns
Reverse recovery charge	Q _{rr}	V _{GS} = 0 V, -dI _{DR} /dt = 100 A/μs		17	_	nC

Note 8: Ensure that the channel temperature does not exceed 175 °C.

7. Marking



8. Characteristics Curves (Note)



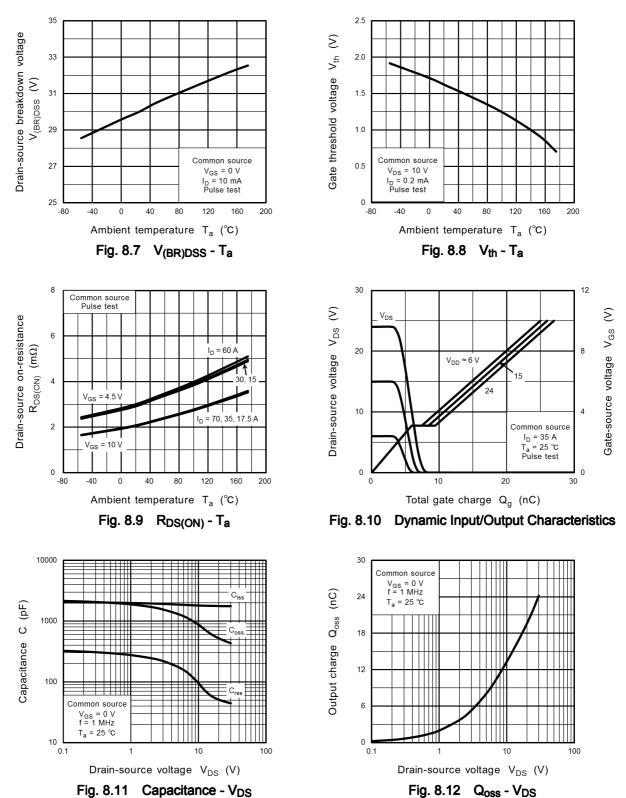
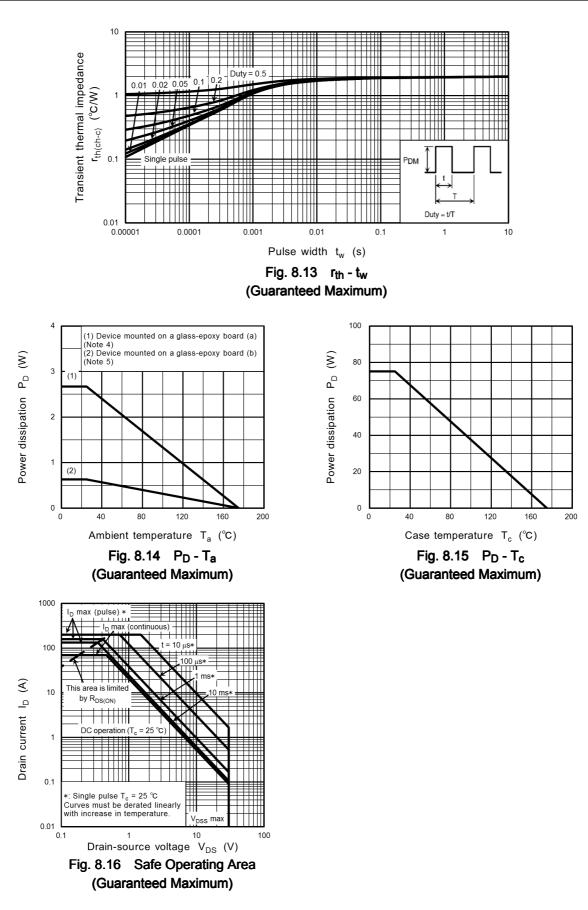


Fig. 8.11 Capacitance - V_{DS}



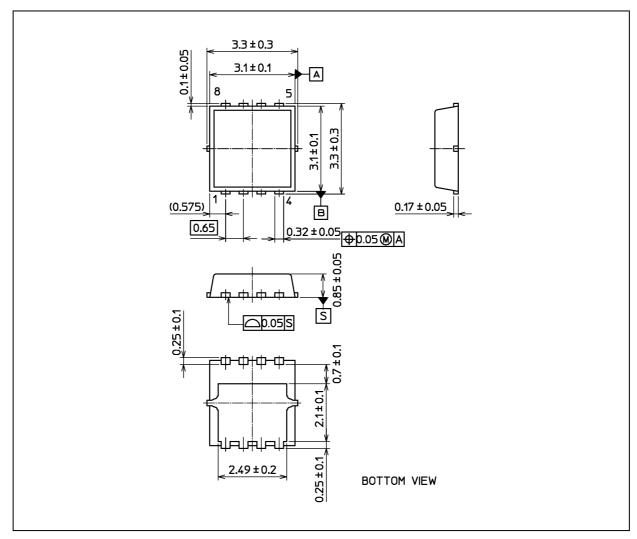
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



TPN2R903PL

Package Dimensions

Unit: mm



Weight: 0.02 g (typ.)

Package Name(s)
TOSHIBA: 2-3X1S
Nickname: TSON Advance

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